

NATIONAL INSTITUTE OF TECHNOLOGY,

TIRUCHIRAPPALLI

DEPARTMENT OF CHEMISTRY

COURSE PLAN – PART I					
Name of the programme and specialization	M.Sc. (Chemistry)				
Course Title	Electronic Structure Methods for Molecular and Solid State Systems				
Course Code	СН 631	No. of Credits	2 Theory + 1 Lab		
Course Code of Pre- requisite subject(s)	Basic knowledge in quantum chemistry is desirable				
Session	January 2021	Section (if, applicable)			
Name of Faculty	Dr. Sunandan Sarkar	Department	Chemistry		
Official Email	ssarkar@nitt.edu	Telephone No.	9153484492		
Name of Course Coordinator(s) (if, applicable)	Dr. R. Karvembu				
Official E-mail	kar@nitt.edu	Telephone No.	9442268653		
Course Type (please tick appropriately)	✓ Core course	Elective course			

Syllabus (approved in BoS)

Ab initio Methods: The Hatree SCF method – the Hatree-Fock equations – Koopmans' theorem – the Roothaan equations – concept of basis sets, electron correlation and configuration interaction, post Hatree-Fock theories.

Density Functional Theory: Principles of DFT – the Hohenberg-Kohn theorems – the Kohn-Sam equations – local density approximation (LDA), exchange-correlation functionals – gradient corrected functionals, hybrid functional and range separated hybrid functionals, DFT methods for van der Waals interactions, general performance overview of DFT.

Molecular Properties and Analysis: Predicting molecular geometry, optimization algorithms, potential energy surfaces (PES), frequencies analysis, zero-point energies and thermodynamic corrections, population analysis, natural bond order (NBO) analysis, molecular electrostatic potential, multipole moments, estimation of electron affinity (EA) and ionization potential (IP), computing molecular orbitals energies. Molecules in complex environments – Polarizable Continuum Models (PCM).

Surfaces and Low Dimensional Solids: Modelling strategies of periodic solids – lattice constants optimization, surface reconstruction, computing band structures and band gaps, density of states, quantum confinement effect, electronic structure of 1D and 0D systems, modification of electronic gap – designing of hybrid nanostructures. Quantum mechanical simulation of large systems – density functional tight binding (DFTB) approach.

Electronic Excited States: Time-dependent methods, vertical excitations, computing transition dipole moment, dark and bright states, analysis of natural transition orbitals (NTOs), attachment and detachment



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densities, properties of charge transfer states. Excited-state optimization, computing emission energy, crossing between potential energy surfaces, conical intersections, electronic couplings between excited states. Applications in LED and Solar cells.

Practical Sessions (Programming, Modelling and Simulation):

1. Bash command and shell scripting and the basic structure of FORTRAN program.

2. Molecular modelling and visualization techniques. Searching for minimum energy structure – geometry optimization and computing the potential energy surface.

3. Frequency calculations – predicting IR spectra, computing normal modes, zero-point energy and thermochemical analysis.

4. Determination of the basis set required to predict the accurate structure, Conventional solution to the basis set superposition error (BSSE) – counterpoise correction.

5. Single point calculations – Mulliken population, NBO analysis, electrostatic potential, multipole moments, IP and EA, energies of HOMO and LUMO.

6. Basic of periodic system calculation – super cell approach, lattice parameter optimization, computing band structure, surface reconstruction, calculation of low dimensional solids.

7. Calculation of excited states properties – computing absorption spectra, visualization and plotting of attachment and detachment densities, characterization of charge transfer states.

8. Excited state geometry optimization - computing the emission energy. Solvent effects.

COURSE OBJECTIVES Introduction to electronic structure methods (quantum chemical approach) for molecular and solid state systems and their use in designing the efficient materials for potential applications.

MAPPING OF COs with POs	
Course Outcomes	Programme Outcomes (PO) (Enter Numbers only)
Upon completing the course the student will be able to	
1. Explain the most important concepts of electronic structure theory	PO1, PO3, PO4, PO7, PO8
2. Understand the structure and reactivity of chemical and biological systems	PO2, PO3, PO4, PO7, PO8
3. Discuss the structural and physical properties of solids in different dimensions	PO3, PO4, PO7, PO8
4. Design and optimize the efficient materials for specific potential applications	PO3, PO4, PO7, PO8, PO10

		COURSE PLAN – PART II			
COUR	SE OVERVIEW				
This	course is offered as a ele	ective course. This is a 2 credit theory and	1 credit lab c	ourse and	
three cl	asses will be conducted p	per week.			
COURSE TEACHING AND LEARNING ACTIVITIES (Add more rows)					
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S.No.	Week/Contact Hours	Торіс	Mode of E	,	



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2	III week of January	Hartree product wavefunctions Many electronic wavefunctions	Online
3	IV week of January	Ground state and excited state energies of 2e systems, Concept of Singlet and Triplet states	Online
4	I week of February	The Hatree SCF method – the Hatree-Fock equations - Koopmans' theorem – the Roothaan equations	Online
5	II week of February	concept of basis sets, electron correlation and configuration interaction, post Hatree-Fock theories.	Online
6	III week of February	Density Functional Theory: Principles of DFT – the Hohenberg-Kohn theorems – the Kohn-Sam equations	Online
7	IV week of February	local density approximation (LDA), exchange- correlation functionals – gradient corrected functionals,	Online
8	I week of March	hybrid functional and range separated hybrid functionals, DFT methods for van der Waals interactions, general performance overview of DFT.	Online
9	II week of March	Molecular Properties and Analysis: Predicting molecular geometry, optimization algorithms, potential energy surfaces (PES), frequencies analysis, zero-point energies and thermodynamic corrections,	Online
10	III week of March	population analysis, natural bond order (NBO) analysis, molecular electrostatic potential, multipole moments, estimation of electron affinity (EA) and ionization potential (IP), computing molecular orbitals energies. Molecules in complex environments – Polarizable Continuum Models (PCM).	Online
11	IV week of March	Surfaces and Low Dimensional Solids: Modelling strategies of periodic solids – lattice constants optimization, surface reconstruction, computing band structures and band gaps, density of states, quantum confinement effect, electronic structure of 1D and 0D systems,	Online
12	I week of April	modification of electronic gap – designing of hybrid nanostructures. Quantum mechanical simulation of large systems – density functional tight binding (DFTB) approach.	Online
13	II week of April	Electronic Excited States: Time-dependent methods, vertical excitations, computing transition dipole moment, dark and bright states, analysis of natural transition orbitals (NTOs), attachment and detachment densities, properties of charge transfer states.	Online
14	III week of April	Excited-state optimization, computing emission energy, crossing between potential energy surfaces, conical intersections, electronic couplings between excited states. Applications in LED and Solar cells.	Online



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15	I week of March Practical Sessions (Programming, Modelling and				Online	
			on): Bash command a		and	
			structure of FORTR.			
16	II week of March	week of March Molecular modelling and visualization techniques. Searching for minimum energy structure – geometry				Online
			tion and computing Determination of the			
			he accurate structure,			
			to the basis set superposition error (BSSE) – counterpoise correction.			
17	III week of March	*			Online	
		computin	ng normal modes, z	zero-point energy	and	
		thermocl	nemical analysis.			
18	IV week of March		point calculations -	A A		Online
			nalysis, electrostatic	▲	· 1	
10	X 1 0 4 ¹²		s, IP and EA, energies			0.1
19	I week of April		periodic system ca			Online
			n, lattice parameter op	L · L	0	
			cture, surface recons	situction, calculatio		
20	II week of April			properties – comp	uting	Online
20	II week of April		lculation of excited states properties – computing sorption spectra, visualization and plotting of			Omme
		attachment and detachment densities,				
			rization of charge trar		,	
COUR	SE ASSESSMENT M	ETHODS	(shall range from 4	to 6)		
S.No.	Mode of Assess	sment	Week/Date	Duration	% V	Veightage
Theor	у					
	Test 1		I week of Mar	60 minutes		25
1						
•	Assignment	1	II week of Feb	2 days		10
2	0			,		
6	Test 2	Test 2		60 minutes	1	25
3			II week of April			
	Compensation Asse	ssment*	III week of April	60 minutes	1	25
CPA						
			II week of May	2 hours		30
3	Final Assessment *					
Practi	cals				1	
			IV week April	3 hours (10		10
		iva-voce)		minutes)		
4	LAB assessment (v		1	,	1	
	LAB assessment (v latory; refer to guide	lines on p	bage 4			
*mano	atory; refer to guide		-			
*mano			-	e feedback about	t the c	course shall



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- 1. Feedback from students during class committee meetings.
- 2. Anonymous feedback through questionnaire at the end of the semester.

COURSE POLICY (including compensation assessment to be specified)

MODE OF CORRESPONDENCE (email/ phone etc) ssarkar@nitt.edu; Tel. No.:9153484492

COMPENSATION ASSESSMENT POLICY

1. This assessment is for those students who missed Test I/II due to genuine reasons.

2. Compensation assessment will be conducted during the III week of April. <u>ATTENDANCE POLICY</u> (A uniform attendance policy as specified below shall be followed)

- > At least 75% attendance in each course is mandatory.
- > A maximum of 10% shall be allowed under On Duty (OD) category.
- Students with less than 65% of attendance shall be prevented from writing the final assessment and shall be awarded 'V' grade.

ACADEMIC DISHONESTY & PLAGIARISM

- Possessing a mobile phone, carrying bits of paper, talking to other students, copying from others during an assessment will be treated as punishable dishonesty.
- Zero mark to be awarded for the offenders. For copying from another student, both students get the same penalty of zero mark.
- The departmental disciplinary committee including the course faculty member, PAC chairperson and the HoD, as members shall verify the facts of the malpractice and award the punishment if the student is found guilty. The report shall be submitted to the Academic office.
- The above policy against academic dishonesty shall be applicable for all the programmes.

ADDITIONAL INFORMATION, IF ANY

FOR APPROVAL		
Dr. Sunandan Sarkar S. Sorthar	7. Kanul	deed 2200
Course Faculty	CC- Chairperson	HOD

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<u>Guidelines</u>

- a) The number of assessments for any theory course shall range from 4 to 6.
- b) Every theory course shall have a final assessment on the entire syllabus with at least 30% weightage.
- c) One compensation assessment for absentees in assessments (other than final assessment) is mandatory. Only genuine cases of absence shall be considered.
- d) The passing minimum shall be as per the regulations.

B.Tech. Admitted in				P.G.
2018	2017	2016	2015	
35% or (Class average/2) whichever is greater.		(Peak/3) or (Cl whichever is low	- · · ·	40%

- e) Attendance policy and the policy on academic dishonesty & plagiarism by students are uniform for all the courses.
- Absolute grading policy shall be incorporated if the number of students per course is less than 10.
- g) Necessary care shall be taken to ensure that the course plan is reasonable and is objective.